Old Company Name in Catalogs and Other Documents

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Renesas Electronics website: http://www.renesas.com

April 1st, 2010 Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (http://www.renesas.com)

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RJK0301DPB

Silicon N Channel Power MOS FET Power Switching

REJ03G1338-0900 Rev.9.00 Apr 19, 2006

Features

- High speed switching
- Capable of 4.5V gate drive
- Low drive current
- High density mounting
- Low on-resistance $R_{DS(on)} = 2.3 \ m\Omega \ typ. \ (at \ V_{GS} = 10 \ V)$

Outline

RENESAS Package code: PTZZ0005DA-A (Package name: LFPAK)

1, 2, 3 Source
4 Gate
5 Drain

Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

Item	Symbol	Ratings	Unit
Drain to source voltage	V _{DSS}	30	V
Gate to source voltage	V _{GSS}	+16/ –12	V
Drain current	I _D	60	А
Drain peak current	I _{D(pulse)} Note1	240	А
Body-drain diode reverse drain current	I _{DR}	60	А
Avalanche current	I _{AP} Note 2	30	А
Avalanche energy	E _{AR} Note 2	90	mJ
Channel dissipation	Pch Note3	65	W
Channel to Case Thermal Resistance	θch-C	1.93	°C/W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	−55 to +150	°C

Notes: 1. PW \leq 10 μ s, duty cycle \leq 1%

2. Value at Tch = 25°C, Rg \geq 50 Ω

3. $Tc = 25^{\circ}C$

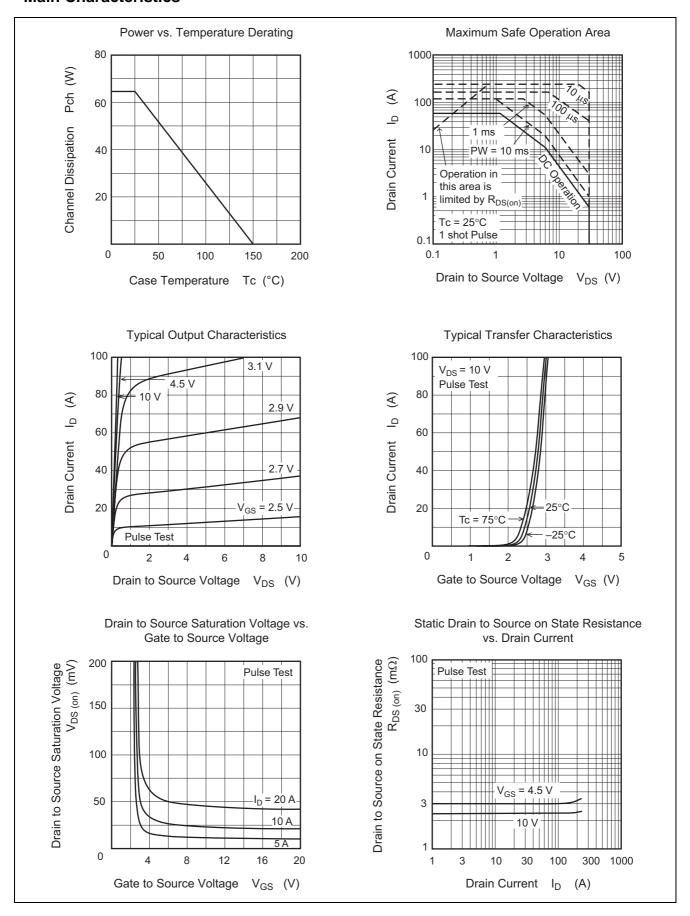
Electrical Characteristics

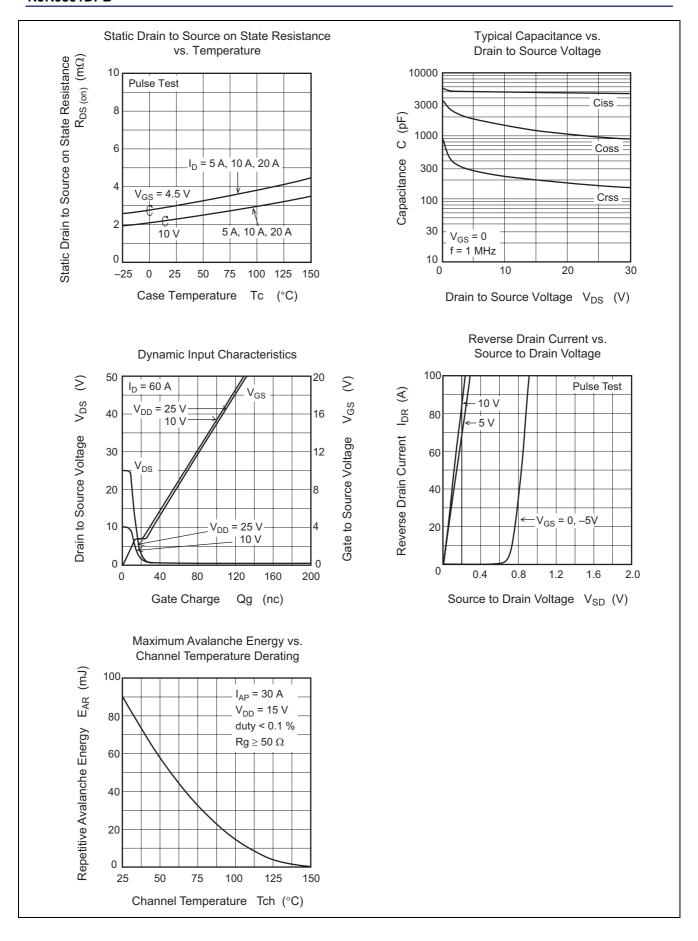
 $(Ta = 25^{\circ}C)$

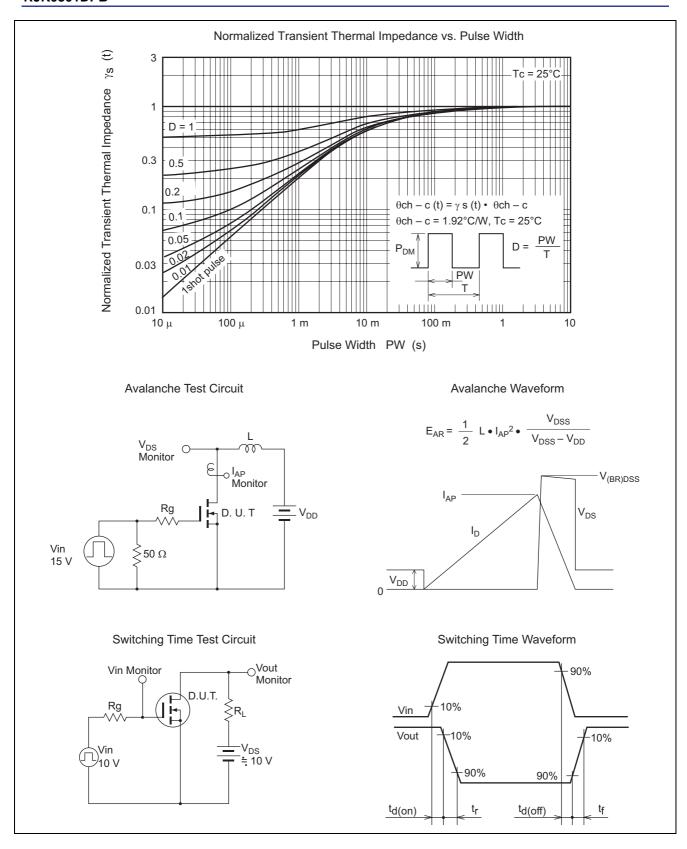
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Drain to source breakdown voltage	$V_{(BR)DSS}$	30	_	_	V	$I_D = 10 \text{ mA}, V_{GS} = 0$
Gate to source leak current	I _{GSS}	_	_	±0.1	μΑ	$V_{GS} = +16/-12 \text{ V}, V_{DS} = 0$
Zero gate voltage drain current	I _{DSS}	_	_	1	μΑ	$V_{DS} = 30 \text{ V}, V_{GS} = 0$
Gate to source cutoff voltage	$V_{GS(off)}$	1.2	_	2.5	٧	$V_{DS} = 10 \text{ V}, I_{D} = 1 \text{ mA}$
Static drain to source on state	R _{DS(on)}	_	2.3	2.8	mΩ	$I_D = 30 \text{ A}, V_{GS} = 10 \text{ V}^{\text{Note4}}$
resistance	R _{DS(on)}	_	3.0	4.0	mΩ	$I_D = 30 \text{ A}, V_{GS} = 4.5 \text{ V}^{\text{Note4}}$
Forward transfer admittance	y _{fs}	_	110	_	S	$I_D = 30 \text{ A}, V_{DS} = 10 \text{ V}^{\text{Note4}}$
Input capacitance	Ciss	_	5000	_	pF	$V_{DS} = 10 \text{ V}, V_{GS} = 0,$
Output capacitance	Coss	_	1450	_	pF	f = 1 MHz
Reverse transfer capacitance	Crss	_	220	_	pF	
Gate Resistance	Rg	_	0.8	_	Ω	
Total gate charge	Qg	_	32	_	nC	$V_{DD} = 10 \text{ V}, V_{GS} = 4.5 \text{ V},$
Gate to source charge	Qgs	_	14.5	_	nC	$I_D = 50 \text{ A}$
Gate to drain charge	Qgd	_	7.0	_	nC	
Turn-on delay time	t _{d(on)}	_	11.5	_	ns	$V_{GS} = 10 \text{ V}, I_D = 30 \text{ A},$
Rise time	t _r	_	4.5	_	ns	$V_{DD} \cong 10 \text{ V,R}_L = 0.33 \Omega,$
Turn-off delay time	t _{d(off)}	_	58	_	ns	$Rg = 4.7 \Omega$
Fall time	t _f	_	6.0	_	ns	
Body-drain diode forward voltage	V_{DF}	_	0.84	1.10	V	IF = 60 A, V _{GS} = 0 Note4
Body-drain diode reverse recovery time	t _{rr}	_	50	_	ns	$IF = 60 \text{ A}, V_{GS} = 0$ $d_{IF}/dt = 100 \text{ A}/ \mu \text{s}$

Notes: 4. Pulse test

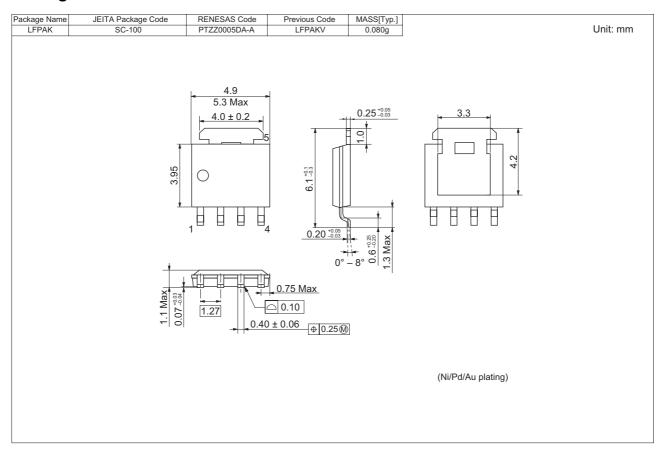
Main Characteristics







Package Dimensions



Ordering Information

Part Name	Quantity	Shipping Container
RJK0301DPB-00-J0	2500 pcs	Taping

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